

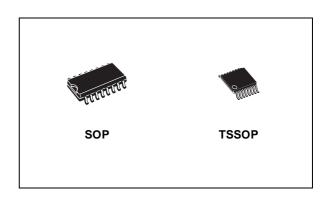
STLVDS3486

HIGH SPEED DIFFERENTIAL LINE RECEIVERS

- MEETS OR EXCEEDS THE REQUIREMENTS OF ANSI TIA/EIA-644 STANDARD
- OPERATES WITH A SINGLE 3.3V SUPPLY
- DESIGNED FOR SIGNALING RATE UP TO 400Mbps
- DIFFERENTIAL INPUT THRESHOLDS ±100mV MAX
- TYPICAL PROPAGATION DELAY TIME OF 2.5ns
- POWER DISSIPATION 60mW TYPICAL PER RECEIVER AT 200MHz
- LOW VOLATGE TTL (LVTTL) LOGIC OUTPUT LEVELS
- PIN COMPATIBLE WITH THE MC3486 AND SN65LVD3486
- OPEN CIRCUIT FAIL SAFE
- ESD PROTECTION:
 7KV RECEIVER PINS
 3KV ALL PINS VS GND

DESCRIPTION

The STLVDS3486, is a differential line receiver that implements the electrical characteristics of low voltage differential signaling (LVDS). This signaling technique lowers the output voltage levels of 5V differential standard levels (such as TIA/EIA-422B) to reduce the power, increase the switching speeds and allow operations with a 3.3V supply rail. This differential receiver provides a



valid logical output state with a 3.3V supply rail. It also provides a valid logical output state with a ±100mV differential input voltage within the input common mode voltage range. The input common mode voltage allows 1V of ground potential difference between two LVDS nodes.

The intended application of this device and signalling technique is both point-to-point and multidrop data transmission over controlled impedance media approximately $100\Omega.$ The transmission media may be printed circuit board traces, backplanes or cables. The ultimate rate and distance of data transfer depend upon the attenuation characteristics of the media and noise coupling to the environment.

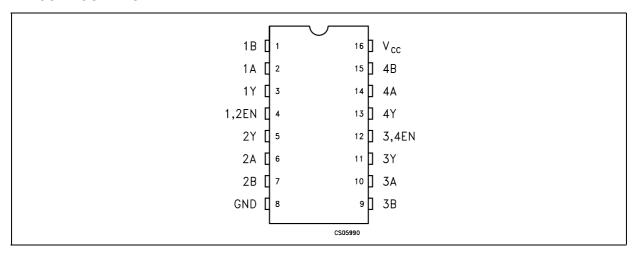
The STLVDS3486 version is characterized for operation from -40°C to 85°C.

ORDERING CODES

Туре	Temperature Range	Package	Comments
STLVDS3486BD	-40 to 85 °C	SO-16 (Tube)	50parts per tube / 20tube per box
STLVDS3486BDR	-40 to 85 °C	SO-16 (Tape & Reel)	2500 parts per reel
STLVDS3486BTR	-40 to 85 °C	TSSOP16 (Tape & Reel)	2500 parts per reel

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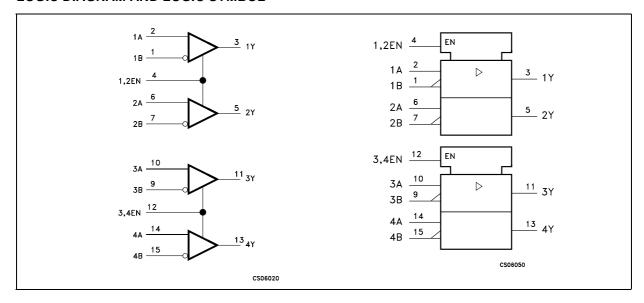
PIN CONFIGURATION



PIN DESCRIPTION

PIN N°	SYMBOL	NAME AND FUNCTION
2, 6, 10, 14	1A to 4A	Receiver Inputs
1, 7, 9, 15	1B to 4B	Negated Receiver Inputs
3, 5, 11, 13	1Y to 4Y	Receiver Outputs
4	1EN, 2EN	Receivers 1 and 2 Enable
12	3EN, 4EN	Receivers 3 and 4 Enable
8	GND	Ground
16	V _{CC}	Supply Voltage

LOGIC DIAGRAM AND LOGIC SYMBOL



TRUTH TABLE

DIFFERENTIAL INPUTS	EBABLES	OUTPUT
A, B	EN	Y
V _{ID} ≥ 100mV	Н	Н
-100mV < V _{ID} < 100mV	Н	?
V _{ID} ≤ -100mV	Н	L
X	L	Z
OPEN	Н	Н

L = Low level, H = High Level, X = Don't care, Z = High Impedance, ? = Indeterminate

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	Supply Voltage (Note 1)		-0.5 to 4.6	V
VI	Input Voltage		-0.5 to (V _{CC} + 0.5)	V
V _I	Input Voltage (A or B inputs)	put Voltage (A or B inputs)		V
ESD	Human Body Model	Pins Receivers	7	KV
ESD		All Pins vs GND	3	ΚV
T _{stg}	Storage Temperature Range		-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Note 1: All voltages except differential I/O bus voltage, are with respect to the network ground terminal.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{CC}	Supply Voltage	3.0	3.3	3.6	V
V _{IH}	HIGH Level Input Voltage (ENABLE)	2.0			V
V _{IL}	LOW Level Input Voltage (ENABLE)			0.8	V
V _{ID}	Magnitude of Differential Input Voltage	0.1		0.6	V
V _{IC}	Common Mode Input Voltage	0.5 V _{ID}		2.4-0.5 V _{ID}	V
				V _{CC} - 0.8	
T _A	Operating Temperature Range	-40		85	°C

ELECTRICAL CHARACTERISTICS (Over recommended operating conditions unless otherwise noted. All typical values are at $T_A = 25^{\circ}C$, and $V_{CC} = 3.3V$)

	,	, 		I		
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{ITH+}	Positive Going Differential Input Voltage Threshold				100	mV
V _{ITH-}	Negative Going Differential Input Voltage Threshold		-100			mV
V _{OH}	High Level Output Voltage	I _{OH} = -8mA	2.4			V
		I _{OH} = -4mA	2.8			
V _{OL}	Low Level Output Voltage	I _{OH} = 8mA			0.4	V
I _{CC}	Supply Current	Enabled, No Load		10	18	mA
		Disabled		0.25	0.5	mA
I _I	Input Current (A or B inputs)	$V_I = 0V$	-2	-10	-20	μΑ
		V _I = 2.4V	-1.2	-3		
I _{I(OFF)}	Power off Input Current (A or B inputs)	$V_{CC} = 0$ $V_I = 3.6V$		10	20	μΑ
I _{IH}	High Level Input Current (EN, G, G or Inputs)	V _{IH} = 2V			10	μА
I _{IL}	Low Level Input Current (EN, G, G or Inputs)	V _{IL} = 0.8V			10	μА
l _{OZ}	High Impedance Output Current	$V_O = 0$ or V_{CC}			± 10	μΑ

SWITCHING CHARACTERISTICS (Unless otherwise noted. Typical values are referred to $T_A = 25$ °C and $V_{CC} = 3.3V$)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t _{PLH}	Propagation Delay Time, Low to High Output	C _L = 10pF Fig. 1	1.5	2.5	3.3	ns
t _{PHL}	Propagation Delay Time, High to Low Output		1.5	2.5	3.3	ns
t _r	Differential Output Signal Rise Time			0.4		ns
t _f	Differential Output Signal Fall Time			0.4		ns
t _{sk(O)}	Channel to Channel Output Skew (note1)			0.1	0.3	ns
t _{sk(P)}	Pulse Skew (t _{PHL} - t _{PLH}) (note2)			0.2	0.4	ns
t _{sk(PP)}	Part to Part Skew (note3)				1	ns
t _{PZH}	Propagation Delay Time, High Impedance to High Level Output	Fig. 2		3	12	ns
t _{PZL}	Propagation Delay Time, High Impedance to Low Level Output			5	12	ns
t _{PHZ}	Propagation Delay Time, High Level to High Impedance Output			5	12	ns
t _{PLZ}	Propagation Delay Time, Low Level to High Impedance Output			5	12	ns

Note 1: t_{sk(O)} is the maximum delay time difference between the propagation delay of one channel and that of the others on the same chip with any event on the inputs.

Note 2: t_{sk(P)} is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.

Note 3: $t_{sk(PP)}$ is the differential channel-to-channel skew of any event between devices. This specification applies to devices at the same V_{CC} , and within 5°C of each other within the operating temperature range.

 V_{ID} C_L=10pF = $V_{IA} V_{IB}$ CS05920 V_{IA} 1.4 V_{IB} 0.4 V_{ID} 0 -0.4V _ †_{PHL} _ t_{PLH} V_{OH} 80% 80% V_{0} 1.4 1.4 20% 20% V_{OL}

Figure 1: Timing Test Circuit, Timing And Waveforms

Note A: All input pulse are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 50Mpps, pulse width = 10 ± 0.2 ns. Note B: C_L includes instrumentation and fixture capacitance within 6mm of the D.U.T.

CS05940

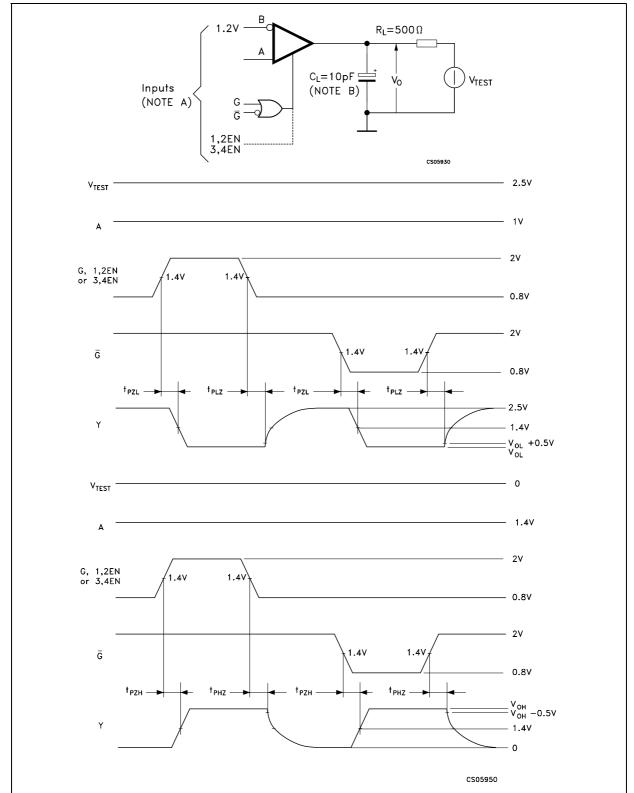


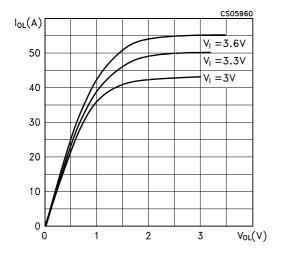
Figure 2: Enable And Disable Time Test Circuit And Waveform

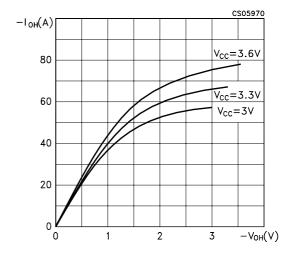
Note A: All input pulse are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 50Mpps, pulse width = 500 ± 10 ns. Note B: C_L includes instrumentation and fixture capacitance within 6mm of the D.U.T.

TYPICAL PERFORMANCE CHARACTERISTICS (unless otherwise specified $T_j = 25$ °C)

Figure 3 : Output Current vs Output Voltage

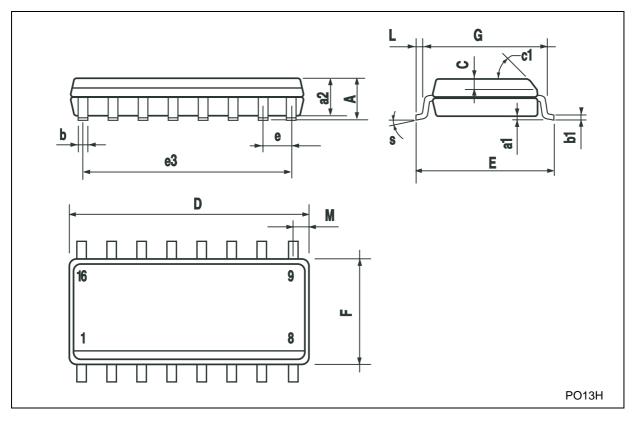
Figure 4 : Output Current vs Output Voltage





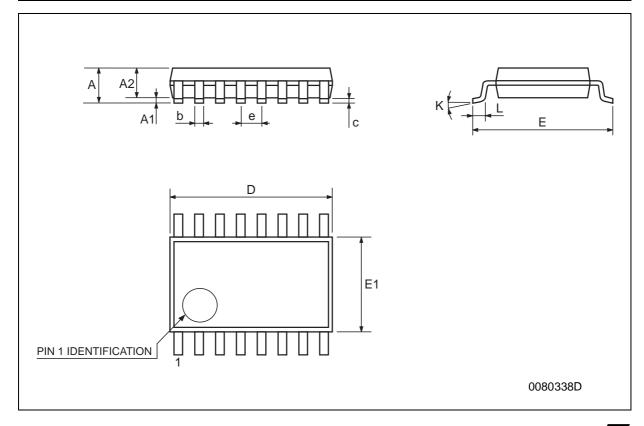
SO-16 MECHANICAL DATA

DIM	mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α			1.75			0.068	
a1	0.1		0.2	0.004		0.008	
a2			1.65			0.064	
b	0.35		0.46	0.013		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.019		
c1			45°	(typ.)		•	
D	9.8		10	0.385		0.393	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		8.89			0.350		
F	3.8		4.0	0.149		0.157	
G	4.6		5.3	0.181		0.208	
L	0.5		1.27	0.019		0.050	
М			0.62			0.024	
S	8		° (r	nax.)	ı	1	



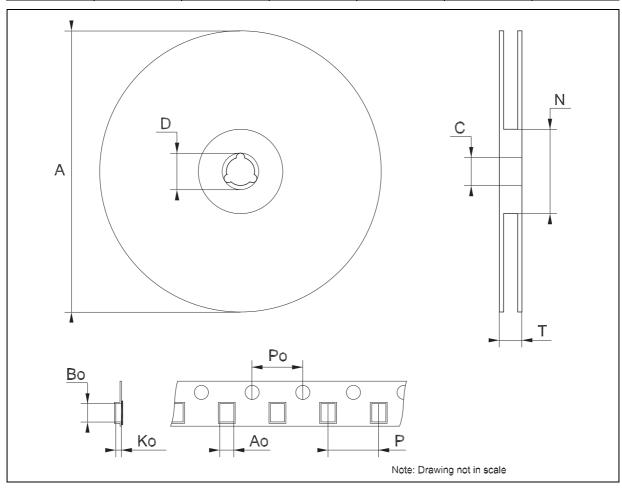
TSSOP16 MECHANICAL DATA

DIM		mm.			inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			1.2			0.047	
A1	0.05		0.15	0.002	0.004	0.006	
A2	0.8	1	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.012	
С	0.09		0.20	0.004		0.0079	
D	4.9	5	5.1	0.193	0.197	0.201	
E	6.2	6.4	6.6	0.244	0.252	0.260	
E1	4.3	4.4	4.48	0.169	0.173	0.176	
е		0.65 BSC			0.0256 BSC		
K	0°		8°	0°		8°	
L	0.45	0.60	0.75	0.018	0.024	0.030	

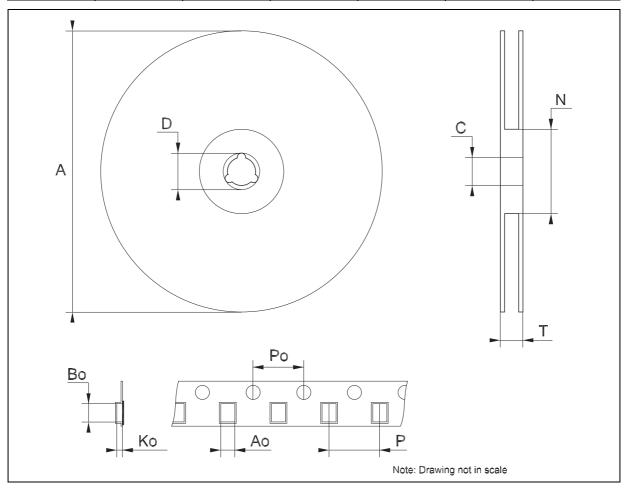


Tape & Reel SO-16 MECHANICAL DATA

D.114	mm.					
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.45		6.65	0.254		0.262
Во	10.3		10.5	0.406		0.414
Ko	2.1		2.3	0.082		0.090
Ро	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



DIM	mm.			inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.7		6.9	0.264		0.272
Во	5.3		5.5	0.209		0.217
Ko	1.6		1.8	0.063		0.071
Ро	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



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